FAIRCHILD

SEMICONDUCTOR

74LVX244 Low Voltage Octal Buffer/Line Driver with **3-STATE** Outputs

General Description

The LVX244 is an octal non-inverting buffer and line driver designed to be employed as a memory address driver, clock driver and bus oriented transmitter or receiver which provides improved PC board density. The inputs tolerate up to 7V allowing interface of 5V systems to 3V systems.

Features

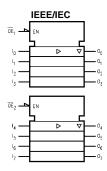
- Input voltage translation from 5V to 3V
- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance

Ordering Code:

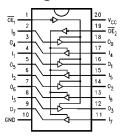
| Order Number | Package Number | Package Description |
|--------------|----------------|---|
| 74LVX244M | M20B | 20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide |
| 74LVX244SJ | M20D | 20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide |
| 74LVX244MTC | MTC20 | 20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide |

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

| | | 17 |
|------------------------------------|--------------------------------------|--|
| | February 1993 | Ę |
| | Revised March 1999 | × |
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| Package | Description | le |
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| 0 ()/ | AJ TYPE II, 5.3mm Wide | ĬŠ |
| all Outline Packag | e (TSSOP), JEDEC MO-153, 4.4mm Wide | Pr |
| the ordering code. | | ₹. |
| Pin Descri | ntions | 5 |
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| Pin Names | Description | E S |
| $\overline{OE}_1, \overline{OE}_2$ | 3-STATE Output Enable Inputs | P |
| I ₀ —I ₇ | Inputs | Ш |
| 0 ₀ -0 ₇ | Outputs | <u>و</u> |
| <i>v</i> / | <u> </u> | f |
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Truth Tables

| Ir | puts | Outputs | | | | |
|-----------------|---------|------------------------------|--|--|--|--|
| OE ₁ | In | (Pins 12, 14, 16, 18) | | | | |
| L | L | L | | | | |
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| н | х | Z | | | | |
| Inputs | | Outputs | | | | |
| Ir | puts | Outputs | | | | |
| | puts | Outputs (Pins 3, 5, 7, 9) | | | | |
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Absolute Maximum Ratings(Note 1)

| Supply Voltage (V _{CC}) | -0.5V to +7.0V |
|--|---------------------------------|
| DC Input Diode Current (IIK) | |
| $V_{I} = -0.5V$ | –20 mA |
| DC Input Voltage (VI) | -0.5V to 7V |
| DC Output Diode Current (I _{OK}) | |
| $V_{O} = -0.5V$ | –20 mA |
| $V_O = V_{CC} + 0.5V$ | +20 mA |
| DC Output Voltage (V _O) | –0.5V to V _{CC} + 0.5V |
| DC Output Source | |
| or Sink Current (I _O) | ±25 mA |
| DC V _{CC} or Ground Current | |
| (I _{CC} or I _{GND}) | ±75 mA |
| Storage Temperature (T _{STG}) | -65°C to +150°C |
| Power Dissipation | 180 mW |

Recommended Operating Conditions (Note 2)

| Supply Voltage (V _{CC}) | 2.0V to 3.6V |
|--|----------------------------------|
| Input Voltage (V _I) | 0V to 5.5V |
| Output Voltage (V _o) | 0V to V _{CC} |
| Operating Temperature (T _A) | $-40^{\circ}C$ to $+85^{\circ}C$ |
| Input Rise and Fall Time ($\Delta t/\Delta V$) | 0 ns/V to 100 ns/V |

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

| Symbol | Parameter | V _{cc} | T _A = +25°C | | $T_{A}=-40^{\circ}C$ to $+85^{\circ}C$ | | Units | Conditions | | |
|-----------------|--------------------------|-----------------|------------------------|---------|--|------|-------|------------|--------------------------------------|--------------------------|
| Symbol | | •cc | Min | Min Typ | | Min | Max | Units | Conditi | 0115 |
| VIH | HIGH Level Input | 2.0 | 1.5 | | | 1.5 | | | | |
| | Voltage | 3.0 | 2.0 | | | 2.0 | | V | | |
| | | 3.6 | 2.4 | | | 2.4 | | | | |
| VIL | LOW Level Input | 2.0 | | | 0.5 | | 0.5 | | | |
| | Voltage | 3.0 | | | 0.8 | | 0.8 | V | | |
| | | 3.6 | | | 0.8 | | 0.8 | | | |
| V _{OH} | HIGH Level Output | 2.0 | 1.9 | 2.0 | | 1.9 | | | $V_{IN} = V_{IH} \text{ or } V_{IL}$ | I _{OH} = -50 μA |
| | Voltage | 3.0 | 2.9 | 3.0 | | 2.9 | | V | | I _{OH} = -50 μA |
| | | 3.0 | 2.58 | | | 2.48 | | | | $I_{OH} = -4 \text{ mA}$ |
| V _{OL} | LOW Level Output | 2.0 | | 0.0 | 0.1 | | 0.1 | | $V_{IN} = V_{IH} \text{ or } V_{IL}$ | l _{OL} = 50 μA |
| | Voltage | 3.0 | | 0.0 | 0.1 | | 0.1 | V | | l _{OL} = 50 μA |
| | | 3.0 | | | 0.36 | | 0.44 | | | $I_{OL} = 4 \text{ mA}$ |
| I _{OZ} | 3-STATE Output | 3.6 | | | ±0.25 | | ±2.5 | μA | $V_{IN} = V_{IH} \text{ or } V_{IL}$ | |
| | Off-State Current | | | | | | | | $V_{OUT} = V_{CC}$ or G | ND |
| I _{IN} | Input Leakage Current | 3.6 | | | ±0.1 | | ±1.0 | μΑ | $V_{IN} = 5.5V \text{ or } GN$ | ID |
| I _{CC} | Quiescent Supply Current | 3.6 | | | 4.0 | | 40.0 | μA | $V_{IN} = V_{CC}$ or GN | D |

Noise Characteristics (Note 3)

| Symbol | Parameter | V _{CC} | $T_A = 25^{\circ}C$ | | Units | C _L (pF) | |
|------------------|--|-----------------|---------------------|-------|-------|----------------------|--|
| Cymbol | i arameter | | Тур | Limit | | 0 _L (pr) | |
| V _{OLP} | Quiet Output Maximum Dynamic V _{OL} | 3.3 | 0.5 | 0.8 | V | 50 | |
| V _{OLV} | Quiet Output Minimum Dynamic V _{OL} | 3.3 | -0.5 | -0.8 | V | 50 | |
| V _{IHD} | Minimum HIGH Level Dynamic Input Voltage | 3.3 | | 2.0 | V | 50 | |
| V _{ILD} | Maximum LOW Level Dynamic Input Voltage | 3.3 | | 0.8 | V | 50 | |

Note 3: Input $t_r = t_f = 3 \text{ ns}$

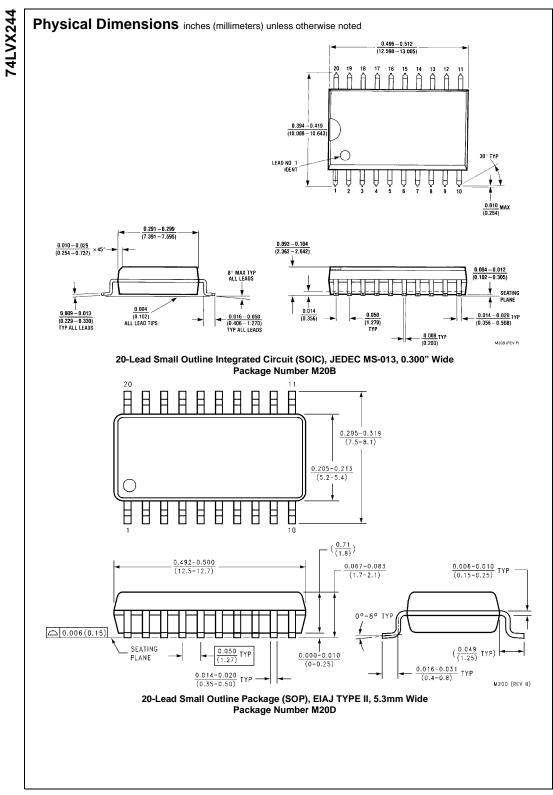
| Symbol | Parameter | V _{cc} | $T_A = +25^{\circ}C$ | | | $T_A=-40^\circ C$ to $+85^\circ C$ | | Units | Conditions |
|-------------------|-------------------|-----------------|----------------------|------|------|------------------------------------|------|-------|-------------------------|
| | Parameter | (V) | Min | Тур | Max | Min | Max | Units | Conditions |
| PLH | Propagation Delay | 2.7 | | 6.1 | 11.4 | 1.0 | 13.5 | | C _L = 15 pF |
| PHL | Time | - | | 8.6 | 14.9 | 1.0 | 17.0 | ns | $C_L = 50 \text{ pF}$ |
| | | 3.3 ± 0.3 | | 4.7 | 7.1 | 1.0 | 8.5 | 115 | C _L = 15 pF |
| | | | | 7.2 | 10.6 | 1.0 | 12.0 | | $C_L = 50 \text{ pF}$ |
| PZL | 3-STATE Output | 2.7 | | 7.1 | 13.8 | 1.0 | 16.5 | | C _L = 15 pF, |
| t _{PZH} | Enable Time | | | | | | | | $R_L = 1 \ k\Omega$ |
| | | | | 9.6 | 17.3 | 1.0 | 20.0 | ns | C _L = 50 pF, |
| | | | | | | | | | $R_L = 1 \ k\Omega$ |
| | | 3.3 ± 0.3 | | 5.5 | 8.8 | 1.0 | 10.5 | | C _L = 15 pF, |
| | | | | | | | | | $R_L = 1 \ k\Omega$ |
| | | | | 8.0 | 12.3 | 1.0 | 14.0 | | C _L = 50 pF, |
| | | | | | | | | | $R_L = 1 \ k\Omega$ |
| PLZ | 3-STATE Output | 2.7 | | 11.6 | 16.0 | 1.0 | 19.0 | ns | C _L = 50 pF, |
| PHZ | Disable Time | 3.3 ± 0.3 | | 9.7 | 11.4 | 1.0 | 13.0 | 115 | $R_L = 1 \ k\Omega$ |
| ^t oslh | Output to Output | 2.7 | | | 1.5 | | 1.5 | ns | $C_L = 50 \text{ pF}$ |
| OSHL | Skew (Note 4) | 3.3 | | | 1.5 | | 1.5 | 115 | |

| Symbol | Parameter | | T _A = +25°C | | T _A =-40°C | Units | |
|--------|--|-----|------------------------|-----|-----------------------|-------|----|
| | Farameter | Min | Тур | Max | Min | Max | |
| CIN | Input Capacitance | | 4 | 10 | | 10 | pF |
| COUT | Output Capacitance | | 6 | | | | pF |
| CPD | Power Dissipation Capacitance (Note 5) | | 19 | | | | pF |

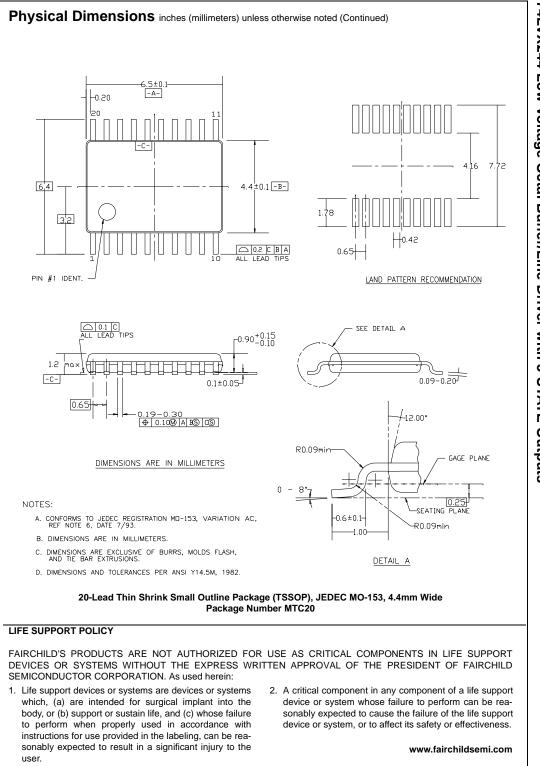
Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation: $l_{CC(opr.)} = \frac{C_{PO} \times V_{CC} \times f_{IN} + l_{CC}}{8 (per bit)}$

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